
	<p><b>SI7884BDP-T1-E3</b></p>
	<p><b>Hersteller-Teilenummer:</b> SI7884BDP-T1-E3</p> <p><b>Hersteller / Marke:</b> Vishay / Siliconix</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 40V 58A PPAK SO-8</p> <p><b>Datenblätter:</b>  SI7884BDP-T1-E3.pdf</p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 104002 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7884BDP-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 40V 58A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	104002 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	4.6W (Ta), 46W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	58A (Tc)
Rds On (Max) @ Id, Vgs	7.5 mOhm @ 16A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	77nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3540pF @ 20V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

SI7884BDP-T1-E3 ist neu im Original, Suche SI7884BDP-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7884BDP-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7884BDP-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>SI7884BDP-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 40V 58A PPAK SO-8</p>	 <p><b>SI7884BDP-TI-E3</b> VISHAT VISHAT PQFN8</p>	 <p><b>SI7884BDP-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 40V 58A PPAK SO-8</p>	 <p><b>SI7882DP-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 12V 13A PPAK SO-8</p>
 <p><b>SI7884DP</b> VISHAY VISHAY QFN</p>	 <p><b>SI7884BDP-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 40V 58A PPAK SO-8</p>	 <p><b>SI7882DP-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 12V 13A PPAK SO-8</p>	 <p><b>SI7884BDP</b> VISHAY SI7884BDP VISHAY</p>

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|  SI7868ADP-T1-E3  |  SI7868ADP-T1-E3  |  SI7868ADP-T1-GE3 |  SI7868ADP-T1-GE3  |  SI7868DP-T1     |
|  SI7868DP-T1-E3   |  SI7868DP-T1-GE3  |  SI786LG-T1       |  SI786LG-T1-E3     |  SI7872DP        |
|  SI7872DP-T1-E3   |  SI7872DP-T1-E3   |  SI7872DP-T1-GE3  |  SI7872DP-T1-GE3   |  SI7880ADP-T1-E3 |
|  SI7880ADP-T1-E3  |  SI7880ADP-T1-GE3 |  SI7880ADP-T1-GE3 |  SI7880DP-T1-GE3   |  SI7882DP-T1-E3  |
|  SI7882DP-T1-E3   |  SI7882DP-T1-GE3  |  SI7882DP-T1-GE3  |  SI7884BDP         |  SI7884BDP-T1-E3 |
|  SI7884BDP-T1-GE3 |  SI7884BDP-T1-GE3 |  SI7884DP-T1-E3   |  SI7884DP-T1-GE3   |  SI7886ADP-T1-E3 |
|  SI7886ADP-T1-E3  |  SI7886ADP-T1-GE3 |  SI7886ADP-T1-GE3 |  SI7886DP          |  SI7886DP-T1     |
|  SI7886DP-T1-E3   |  SI7886DP-T1-GE3  |  SI7888DP-T1-E3   |  SI7888DP-T1-E3    |  SI7888DP-T1-GE3 |
|  SI7888DP-T1-GE3  |  SI7892ADP-T1-E3  |  SI7892ADP-T1-GE3 |  SI7892ADP-T1-GE3. |  SI7892BDP-T1-E3 |
|  SI7892BDP-T1-E3  |  SI7892BDP-T1-GE3 |  SI7892BDP-T1-GE3 |  SI7892DP          |  SI7892DP-T1     |

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